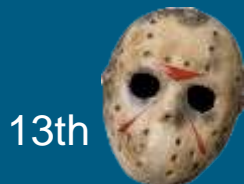


Molecular magnetism goes spintronic

Maciej Misiorny, Michael Hell & Maarten Wegewijs

Peter Grünberg Institut, Forschungszentrum Jülich & JARA, 52425 Jülich, Germany

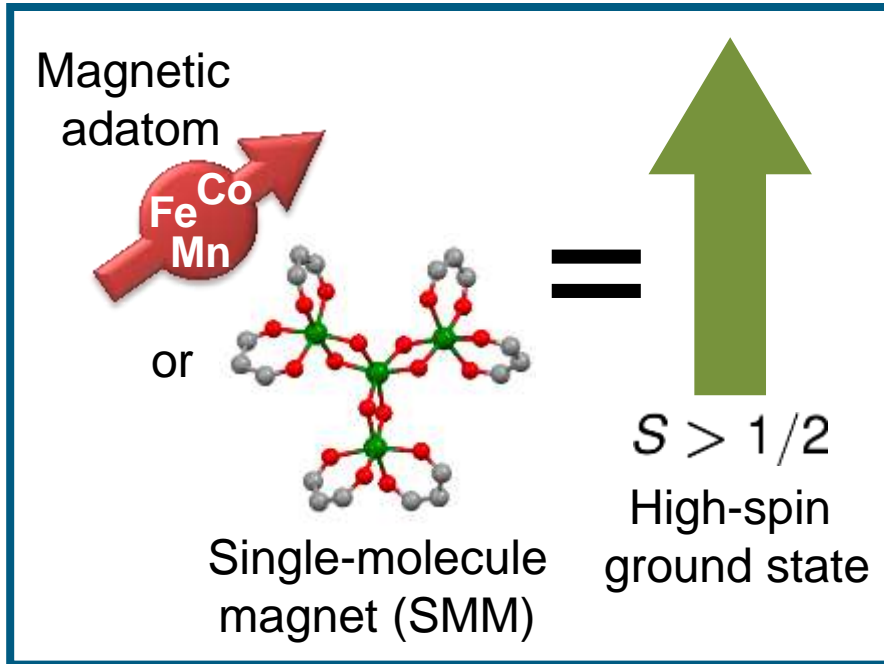
Kavli Institute for Theoretical Physics
University of California



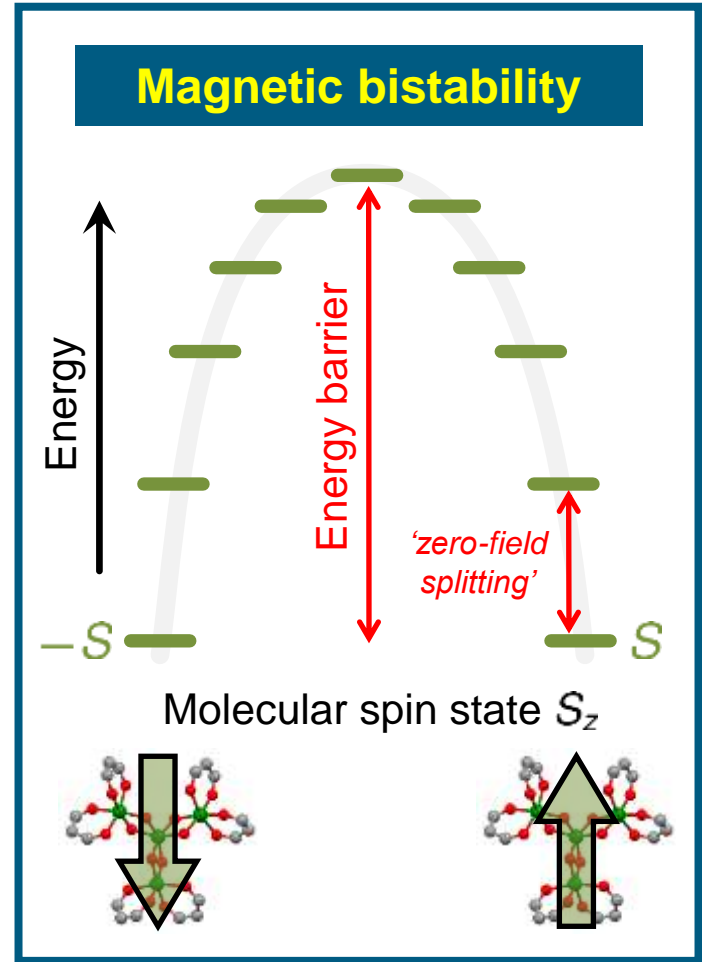
13th December 2013, Santa Barbara



Superparamagnets: why magnetic anisotropy?

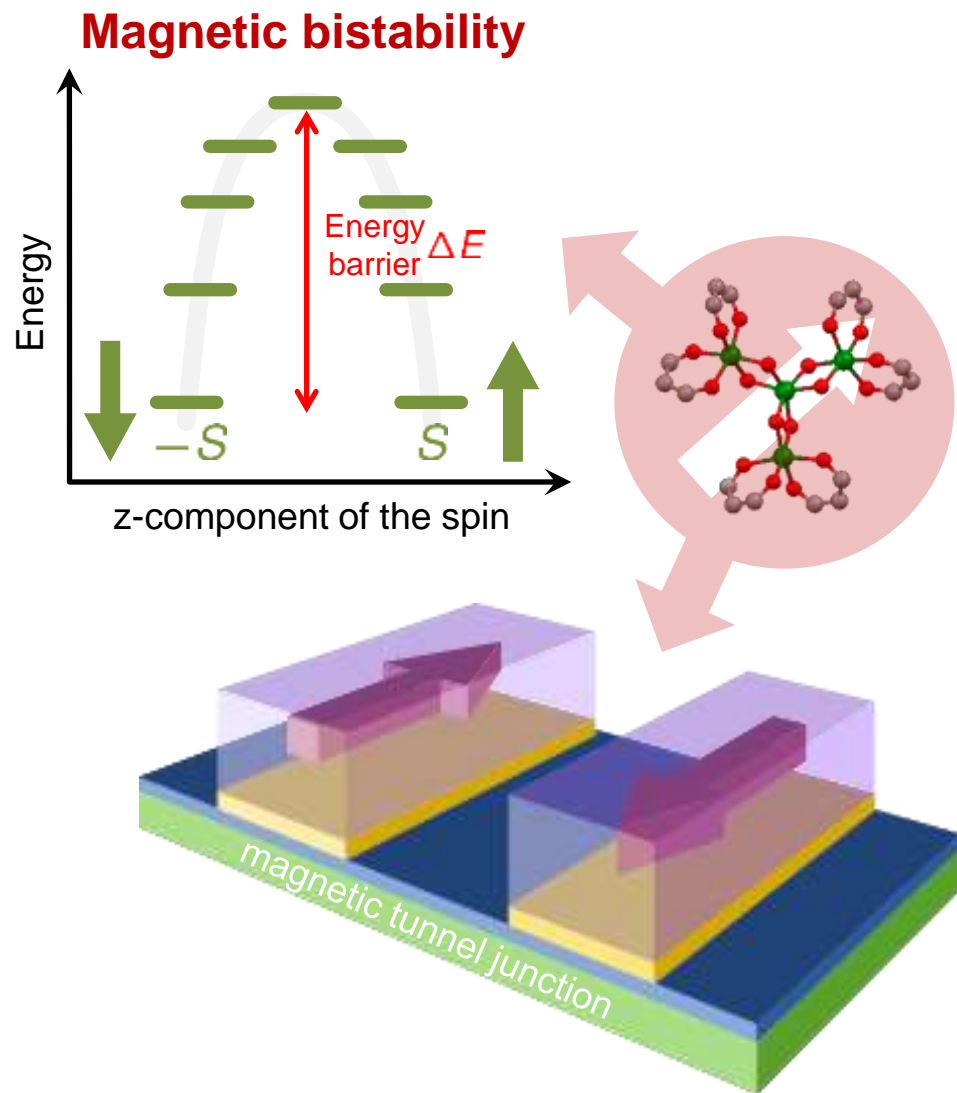


Uniaxial magnetic anisotropy
= preferential orientation along a specific direction



Magnetic bistability = prerequisite for a building block of a memory cell

Motivation: why spin-polarized transport?



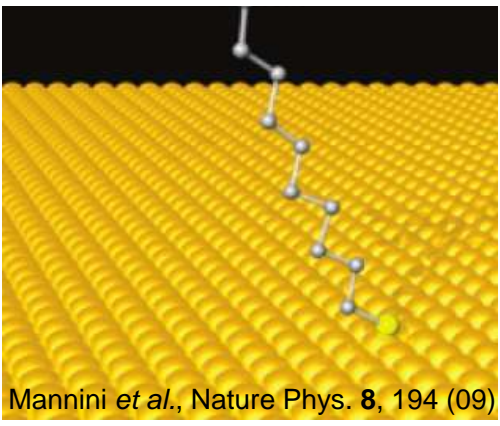
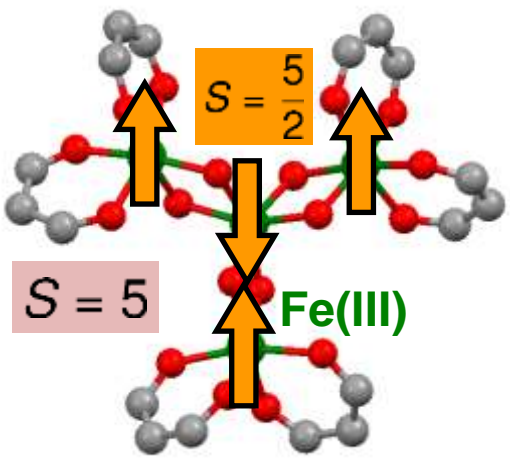
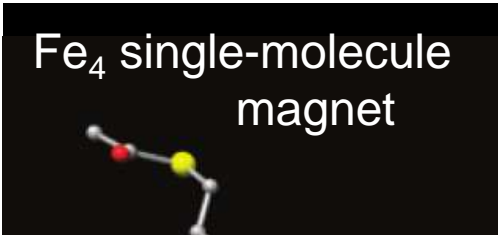
➔ **IDEA:** use *spin-polarized* currents to control magnetic state of SMM

➔ **CHALLENGES:**

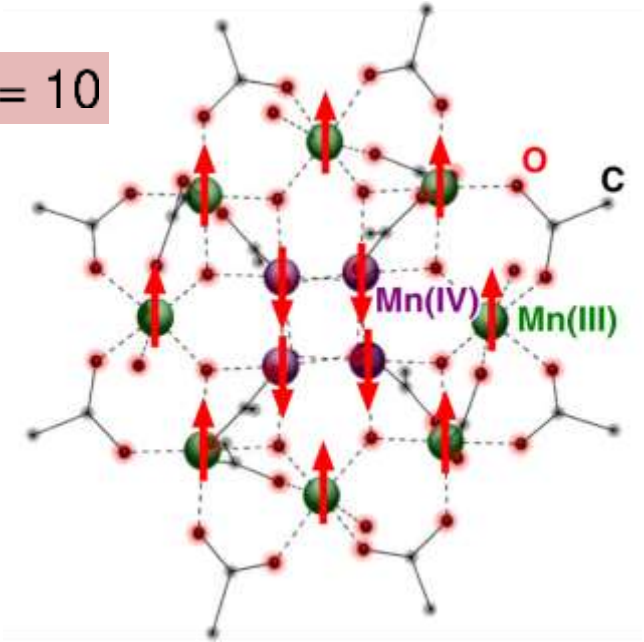
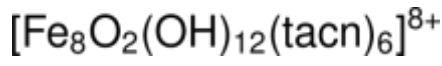
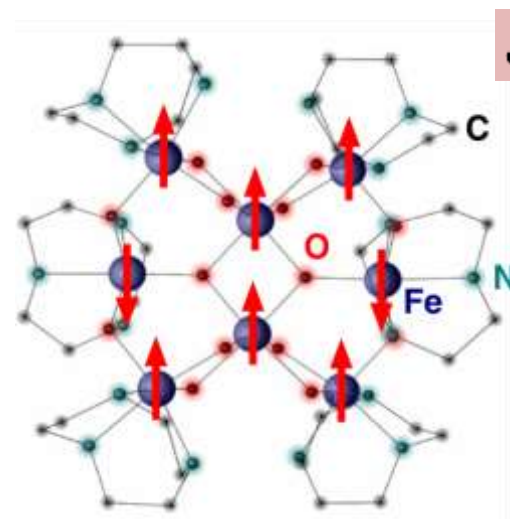
- synthesis of SMMs with large energy barriers
- stability of SMM's magnetic properties when connecting to a electronic/spintronic circuit

➔ **QUESTION:** can one *generate* the effect of molecular magnetism, i.e. magnetic anisotropy, in a **nano**-scopic spintronic system **without** intrinsic anisotropy?

Molecular magnets: magnetism at nanoscale



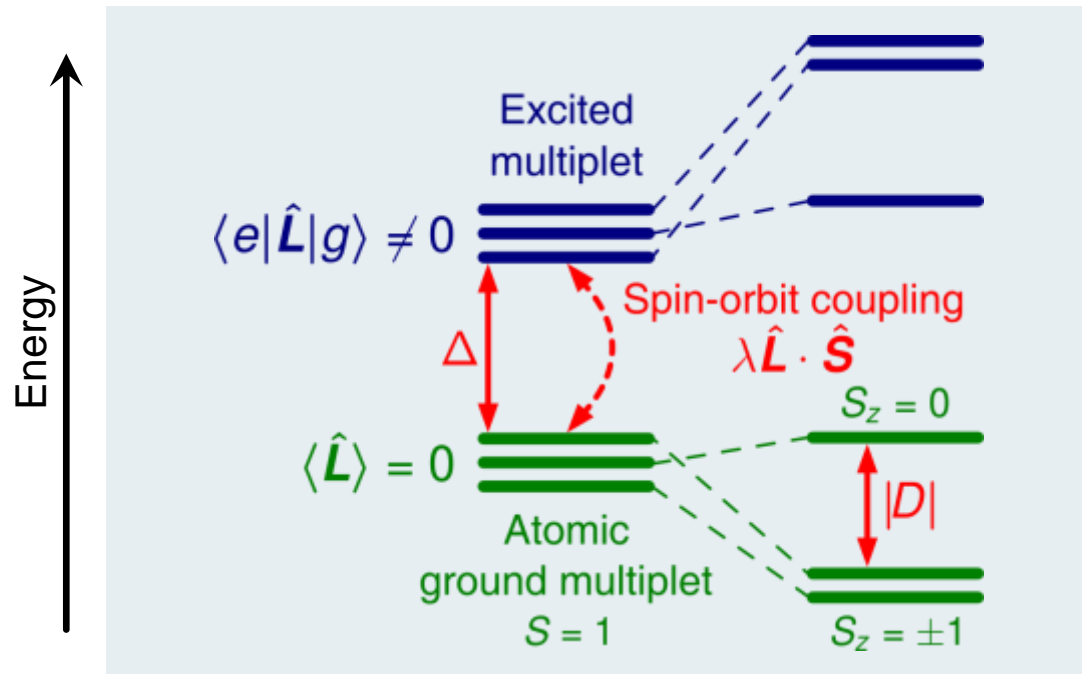
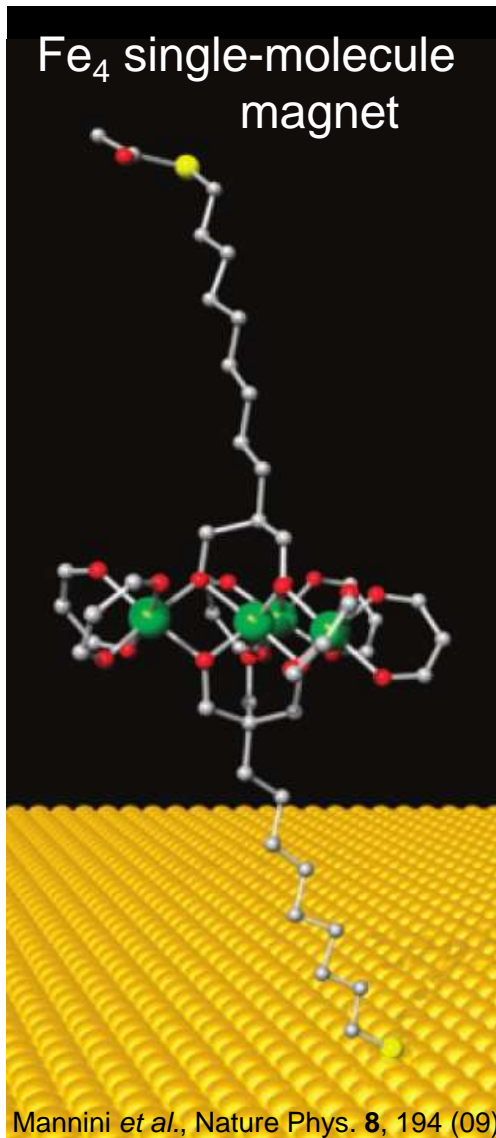
Nanoscopic systems, whose magnetism stems from strong interactions between their magnetic constituents



Uniaxial anisotropy constant: $\left\{ \begin{array}{l} \text{SMMs} \quad |D| \lesssim \text{tens of } \mu\text{eV} \\ \text{magnetic} \\ \text{adatoms} \quad |D| \lesssim \text{a few meV} \end{array} \right.$

Aromi & Brechin, Struct. Bond. **122**, 1 (06);
Gatteschi *et al.*, *Molecular nanomagnets*, OUP 2006

The origin of magnetic anisotropy



➔ Effective *giant-spin* Hamiltonian:

$$\mathcal{H}_{\text{eff}} = \mathbf{S} \cdot \mathbf{D} \cdot \mathbf{S} = D \left[S_z^2 - \frac{1}{3} S(S+1) \right] + E(S_x^2 - S_y^2)$$

z-z spin-quadrupole moment: Q_{zz}

$$D_{ij} = -\lambda^2 \frac{\langle g|L_i|e\rangle \langle e|L_j|g\rangle}{\Delta}$$

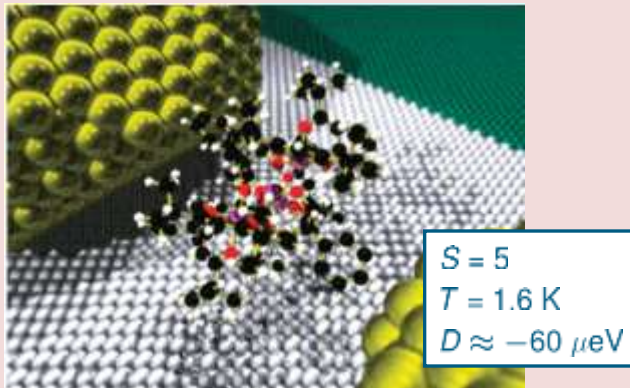
$$D = \frac{3}{2} D_{zz}$$

$$E = \frac{1}{2} (D_{xx} - D_{yy})$$

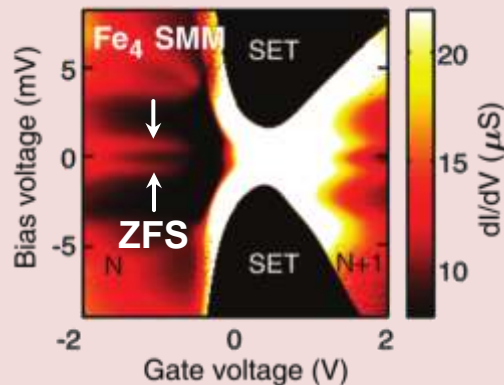
Kahn, *Molecular magnetism*, VCH
Gatteschi *et al.*, *Molecular nanomagnets*, OUP

Electronic transport through molecular magnets

Molecular junction



Zyazin *et al.*, Nano Lett. **10**, 3307 (10)



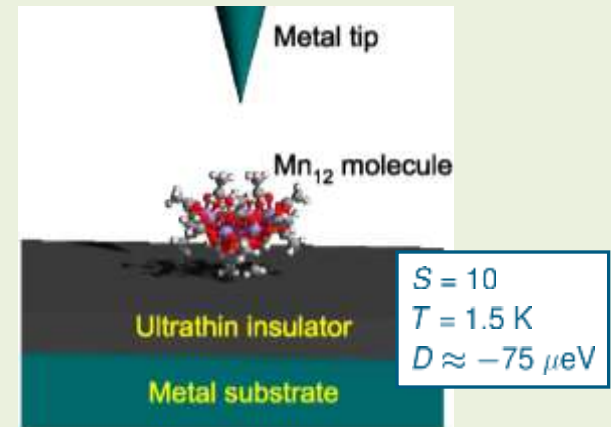
SMM	S	T (K)	D (μeV)
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Heersche <i>et al.</i> , PRL 96 , 206801 (06)	Mn ₁₂	10	1.5-3	- 56
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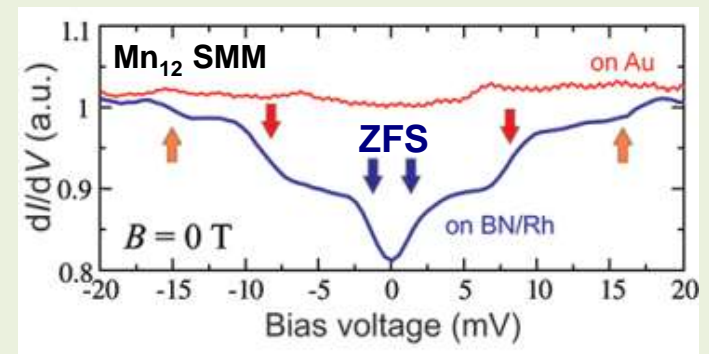
Jo <i>et al.</i> , Nano Lett. 6 , 2014 (06)	Mn ₁₂	10	±0.3	- 70-85
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Burzuri <i>et al.</i> , PRL 109 , 147203 (12)	Fe ₄	5	1.9	- 56
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Scanning tunneling microscope



Kahle *et al.*, Nano Lett. **12**, 518 (12)



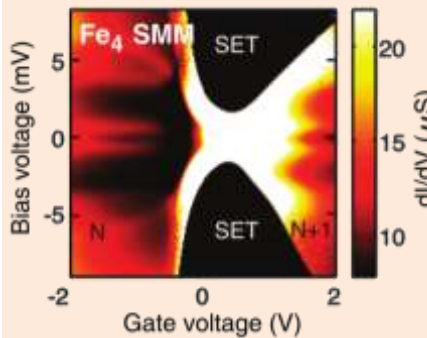
SMM	S	T (K)	
Voss <i>et al.</i> , PRB 78 , 155403 (08)	Mn ₁₂	10	300

Is tuning of magnetic anisotropy possible?

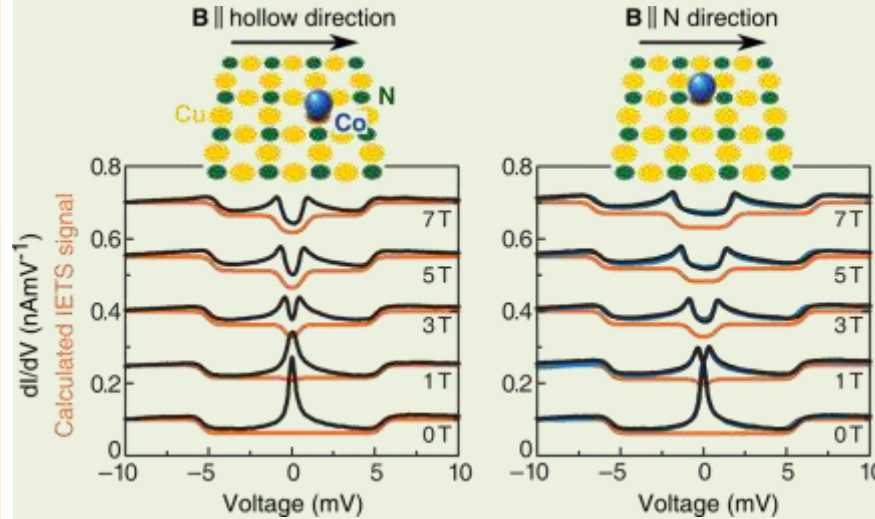
electric field

Zyazin *et al.*, Nano Lett. **10**, 3307 (10)

Burzuri *et al.*, PRL **109**, 147203 (12)

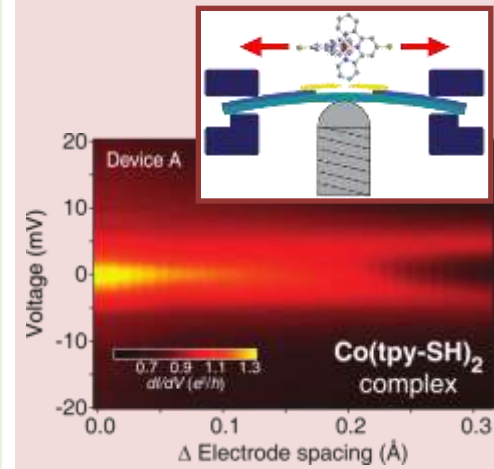


modification of local environment

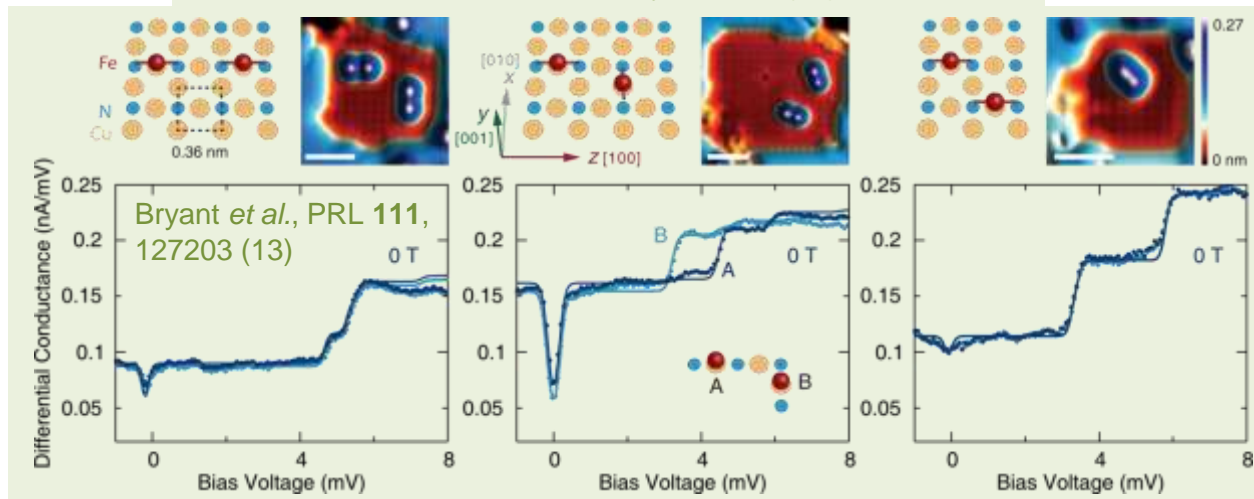


Otte *et al.*, Nature Phys. **4**, 847 (08)

mechanical straining

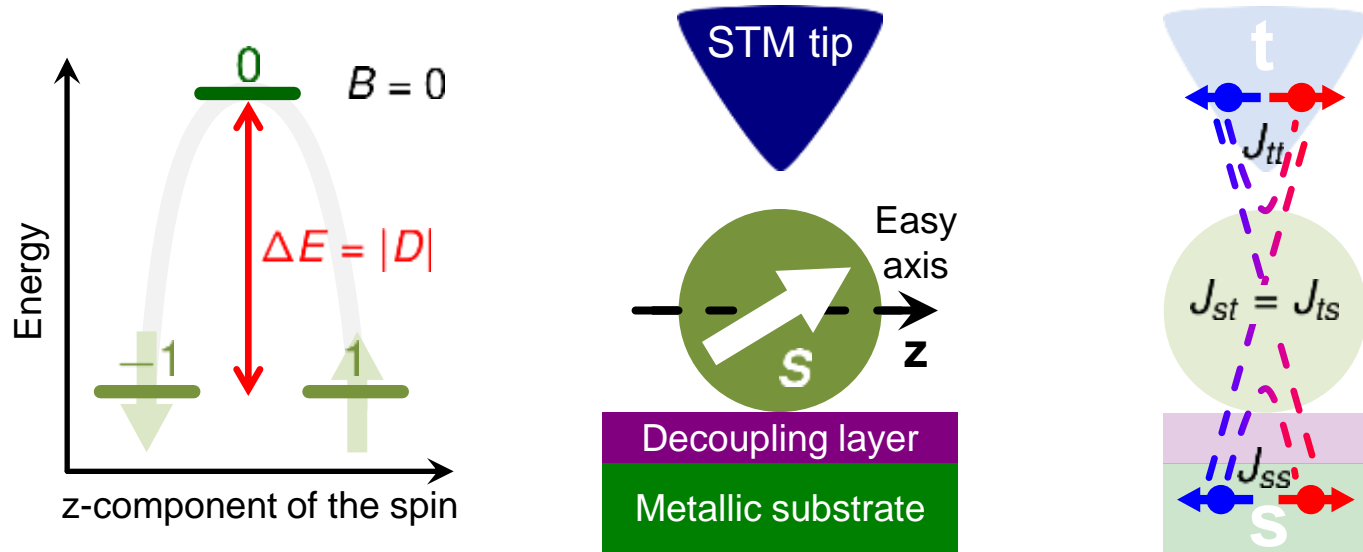


Parks *et al.*, Science **328**, 1370 (10)



Bryant *et al.*, PRL **111**, 127203 (13)

Identification of spin-anisotropy from transport spectra



➔ **nanomagnet:**
the *giant-spin* Hamiltonian

$$\mathcal{H}_{\text{eff}} = BS_z + DQ_{zz}$$

$$\mathcal{H}_{\text{eff}}|m\rangle = E_m|m\rangle \quad \text{and} \quad S_z|m\rangle = m|m\rangle$$

➔ **electron tunneling processes:**
the Appelbaum Hamiltonian

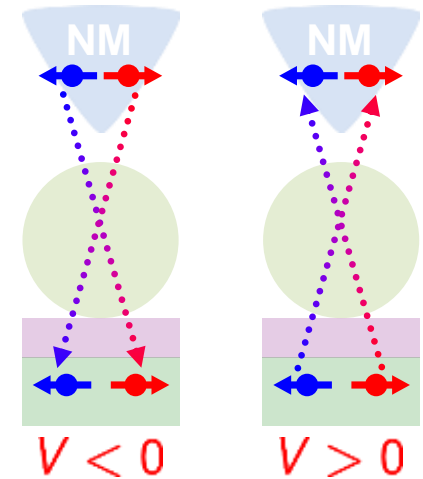
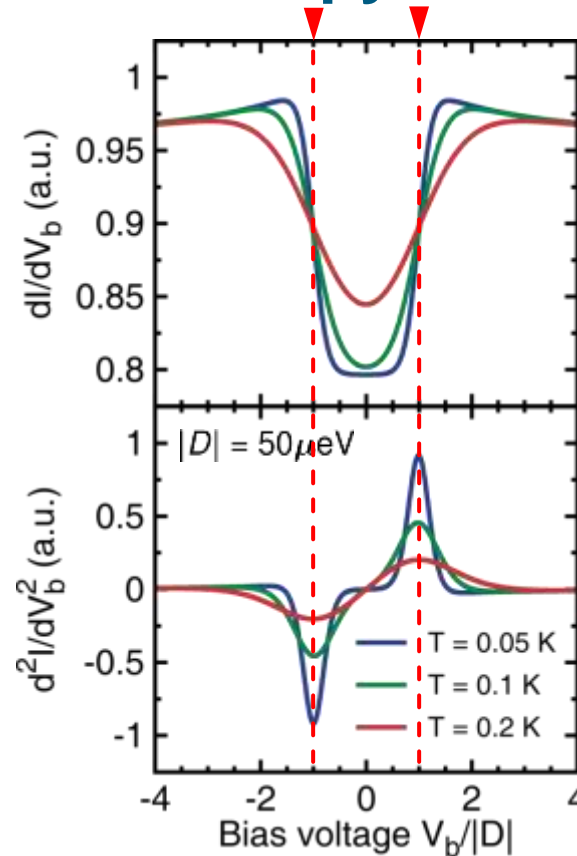
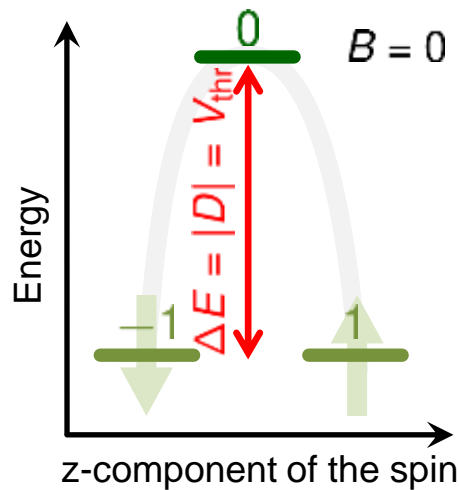
$$\mathcal{H}_{\text{tun}} = \sum_{qkk'\alpha} \left\{ T_d a_{k\alpha}^{q\dagger} a_{k'\alpha}^{\bar{q}} \quad \text{direct tunneling} \right. \\ \left. + \sum_{q'\beta} J_{qq'} \sigma_{\alpha\beta} \cdot \mathbf{S} a_{k\alpha}^{q\dagger} a_{k'\beta}^{q'} \right\}$$

↙ elastic/inelastic scattering

$$S_- a_{k\uparrow}^{q\dagger} a_{k'\downarrow}^{q'} + S_+ a_{k\downarrow}^{q\dagger} a_{k'\uparrow}^{q'} + S_z \left[a_{k\uparrow}^{q\dagger} a_{k'\uparrow}^{q'} - a_{k\downarrow}^{q\dagger} a_{k'\downarrow}^{q'} \right]$$

Identification of spin-anisotropy from transport spectra

weak coupling

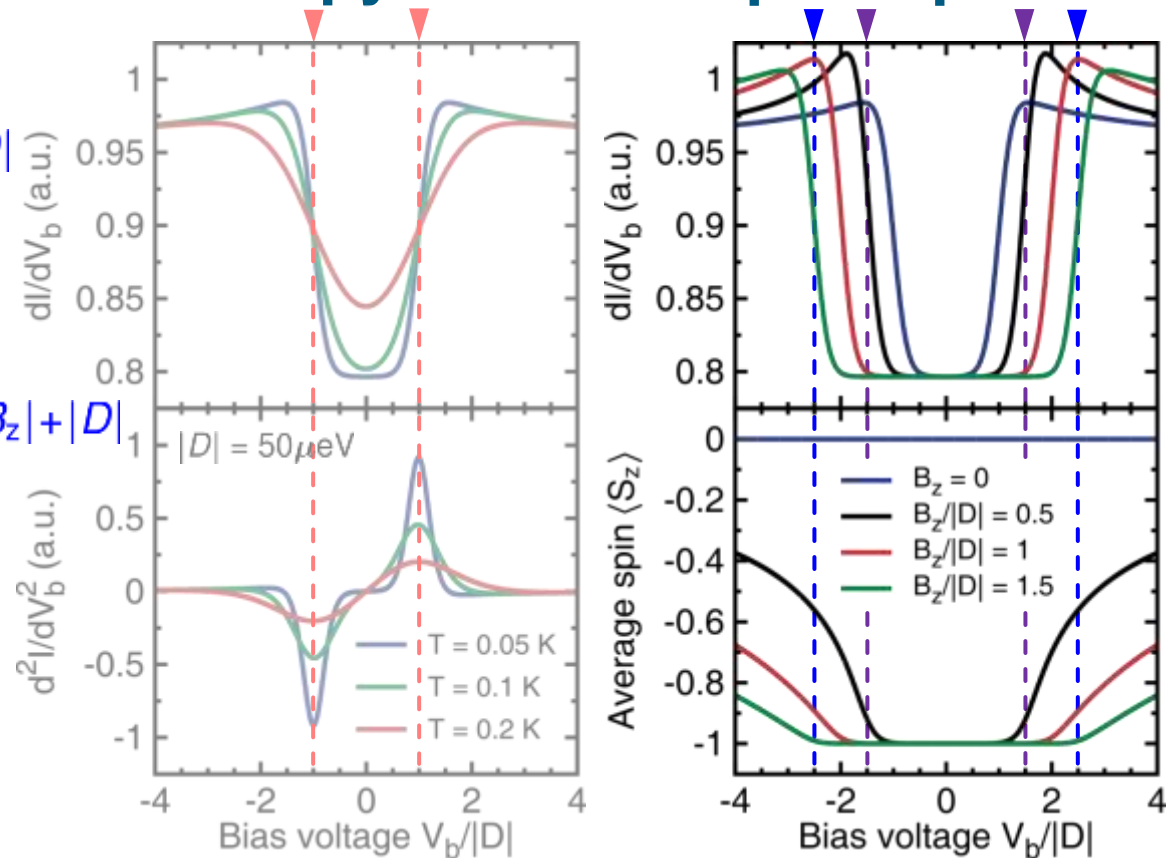
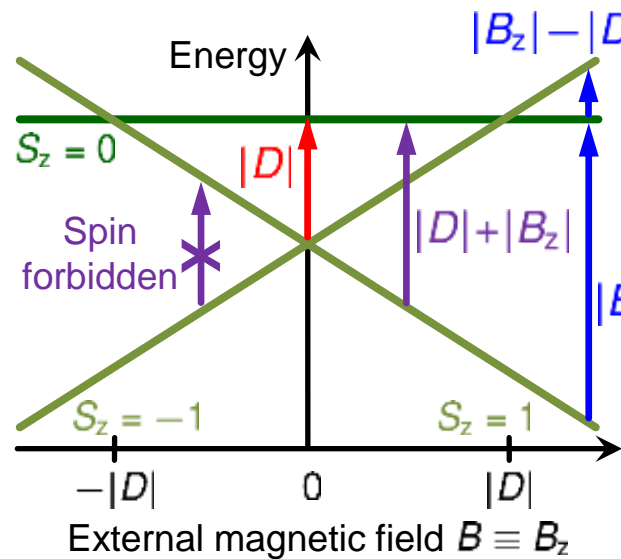


- ➔ at low T and V_b the two metastable ground states $|\pm S\rangle$ occupied with equal probabilities
- ➔ for $|V_b| \approx V_{\text{thr}} \equiv D(2S - 1)$ the **inelastic** transport processes become activated
- ➔ **symmetric** inelastic conduction electron-spin scattering processes

MM & Barnaś, PRB **75**, 134425 (07); PRL **111**, 046603 (13); see also Fransson *et al.*, Bode *et al.*, Delgado *et al.*, Elste & Timm;
Experiments: Hirjibehedin *et al.*, Science **312**, 1021 (06); Jo *et al.*, Nano Lett. **6**, 2014 (06); Zyazin *et al.*, Nano Lett. **10**, 3307 (10);
 Kahle *et al.*, Nano Lett. **12**, 518 (12)

Identification of spin-anisotropy from transport spectra

weak coupling



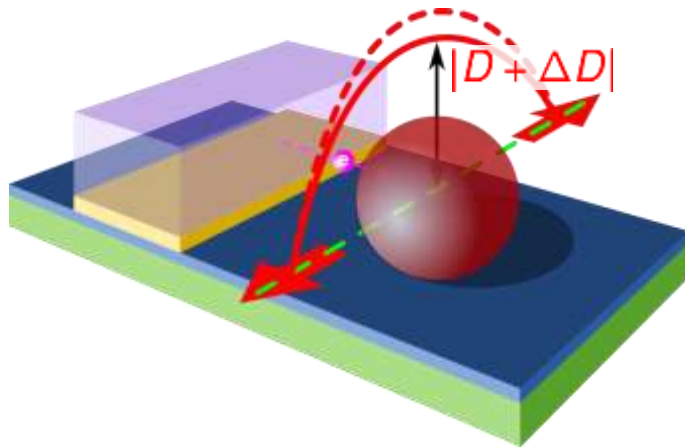
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MM & Barnaś, PRB **75**, 134425 (07); PRL **111**, 046603 (13); see also Fransson *et al.*, Bode *et al.*, Delgado *et al.*, Elste & Timm;
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 Kahle *et al.*, Nano Lett. **12**, 518 (12)

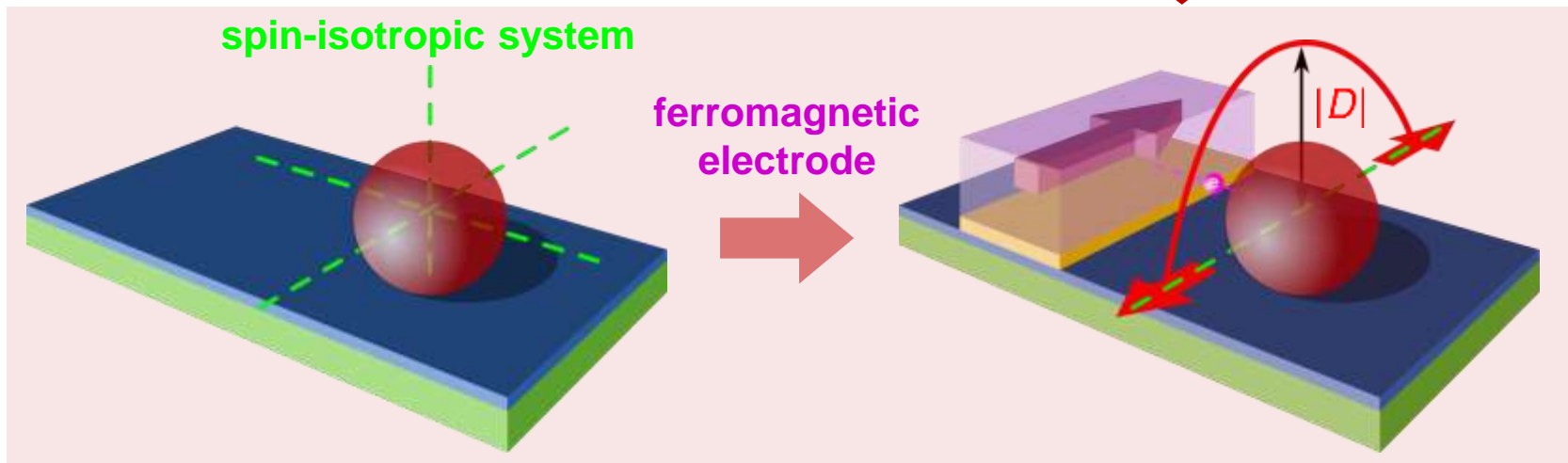
Molecular magnetism goes spintronic

- ➔ let's increase the strength of **tunnel coupling** and allow **charge fluctuation**
- ➔ **intrinsic magnetic anisotropy + charge fluctuations = anisotropy renormalization**

MM, Weymann & Barnaś, PRB **86**, 245415 (12)



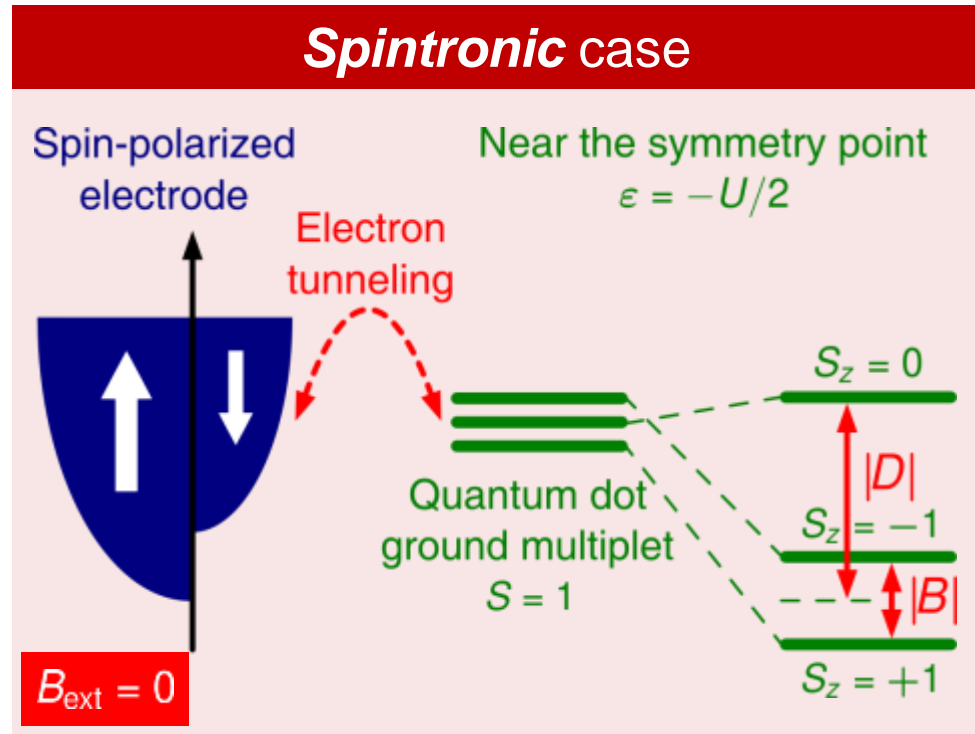
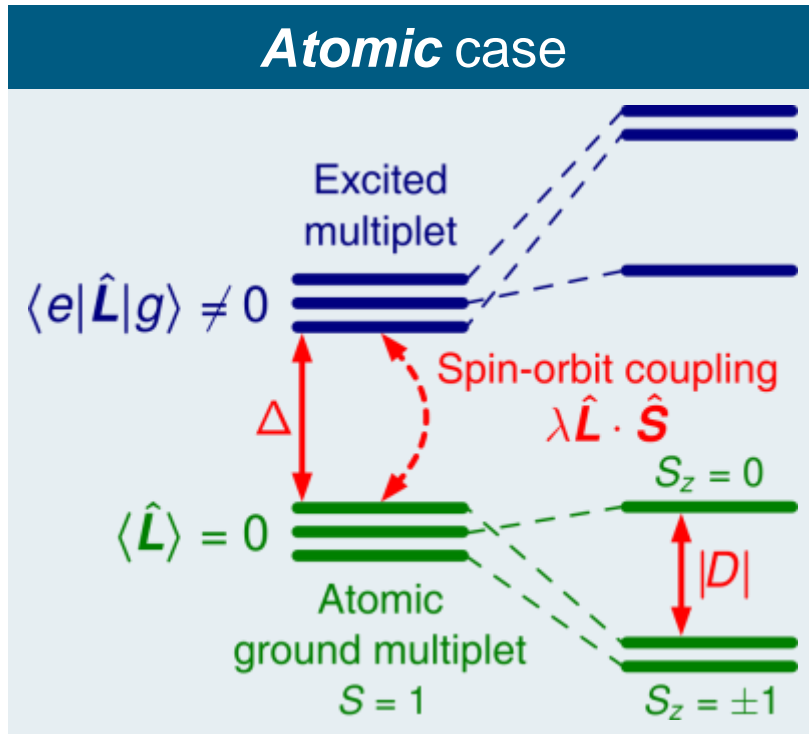
Can one generate spin-anisotropy
in a nanoscopic spintronic system
without intrinsic anisotropy?



MM, Hell & Wegewijs, Nature Phys. **9**, 801 (13)

Atomic vs. spintronic origin of magnetic anisotropy

➔ Effective *giant-spin* Hamiltonian: $\mathcal{H}_{\text{eff}} = BS_z + DQ_{zz}$ z-z spin-quadrupole moment:
 $Q_{zz} = S_z^2 - \frac{1}{3}S(S+1)$



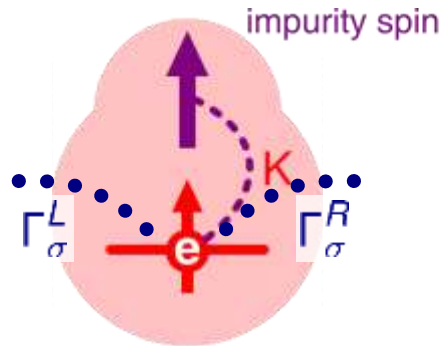
$$B \equiv B_{\text{ext}}$$

$$D = -\frac{3}{2} \frac{\lambda^2 |\langle g | L_z | e \rangle|^2}{\Delta}$$

- ### Spintronic exchange fields
- **DIPOLAR** B (known) Martinek et al., PRL 91, 127203 (03); PRB 72, 121302 (05)
 - **QUADRUPOLAR** D (**NEW!**)

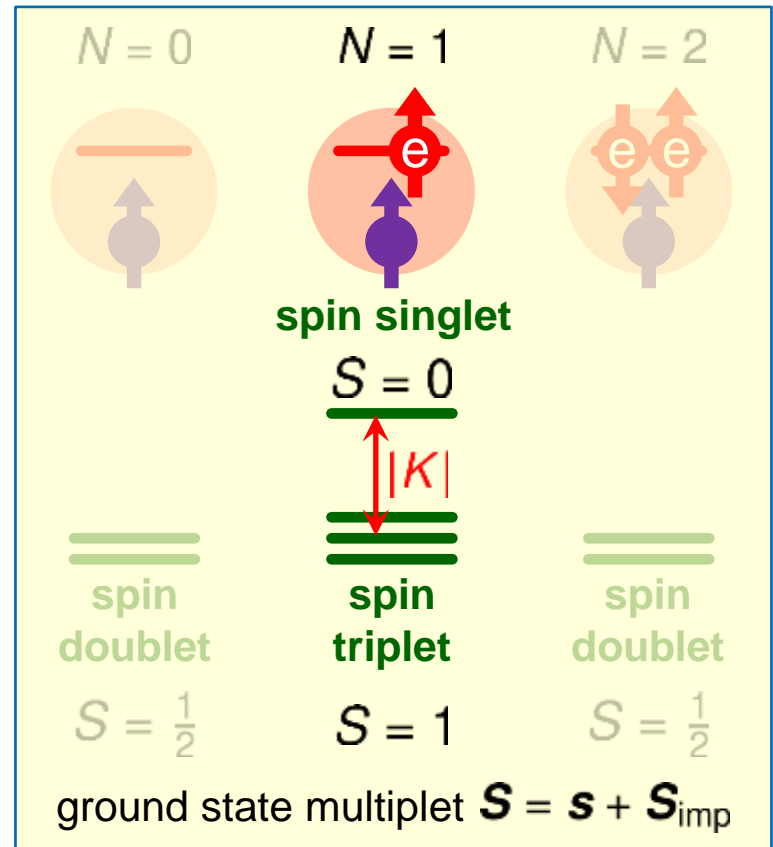
MODEL: high-spin quantum-dot spin valve

Starting point: spin-isotropic system!!!



ferromagnetic exchange coupling

$$\mathcal{H}_{\text{dot}} = \epsilon \sum_{\sigma} n_{\sigma} + U n_{\uparrow} n_{\downarrow} + K \mathbf{s} \cdot \mathbf{S}_{\text{imp}}$$

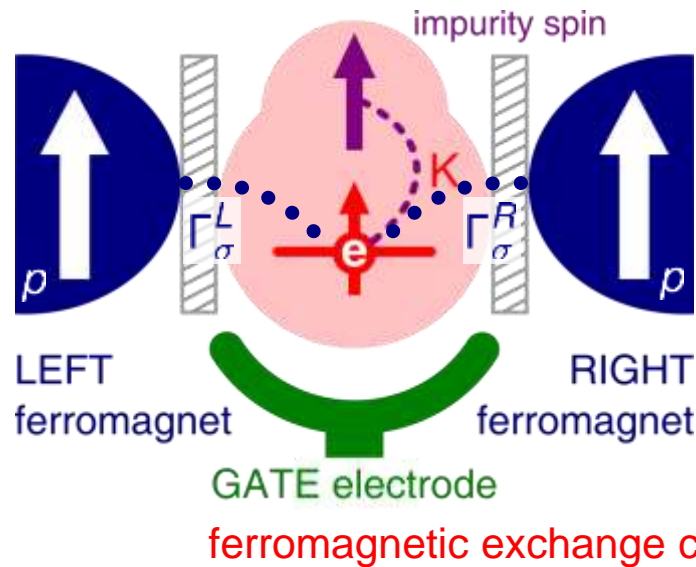


➔ **electron tunneling processes** $\mathcal{H}_{\text{tun}} = \sum_{q\mathbf{k}\sigma} \sqrt{\frac{\Gamma_{\sigma}^q}{\pi\nu_{\sigma}}} d_{\sigma}^{\dagger} a_{\mathbf{k}\sigma}^q + \text{H.c.}$

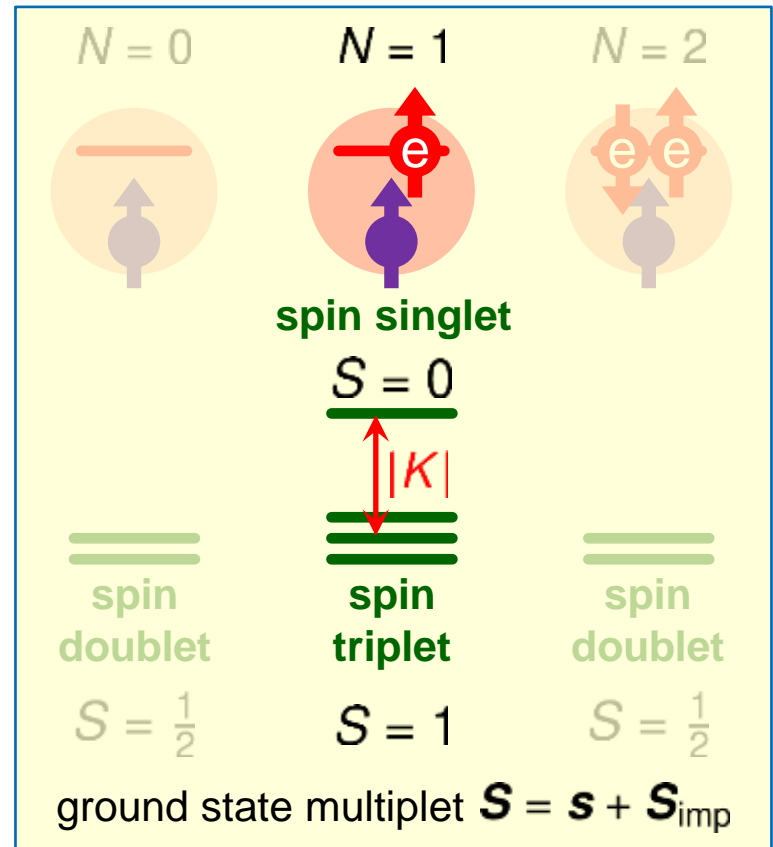
Focus on $N = 1, S = 1$ state: fluctuations into virtual $N = 0, 2$ lead to renormalization

MODEL: high-spin quantum-dot spin valve

Starting point: spin-isotropic system!!!



$$\mathcal{H}_{\text{dot}} = \epsilon \sum_{\sigma} n_{\sigma} + U n_{\uparrow} n_{\downarrow} + K \mathbf{s} \cdot \mathbf{S}_{\text{imp}}$$



➔ **electron tunneling processes** $\mathcal{H}_{\text{tun}} = \sum_{qk\sigma} \sqrt{\frac{\Gamma_{\sigma}^q}{\pi\nu_{\sigma}}} d_{\sigma}^{\dagger} a_{k\sigma}^q + \text{H.c.}$

➔ **IDEA:** electrons localized in a high-spin ($S \geq 1$) **spin-isotropic** quantum dot probe the broken spin symmetry in attached ferromagnets by **virtual charge fluctuations**

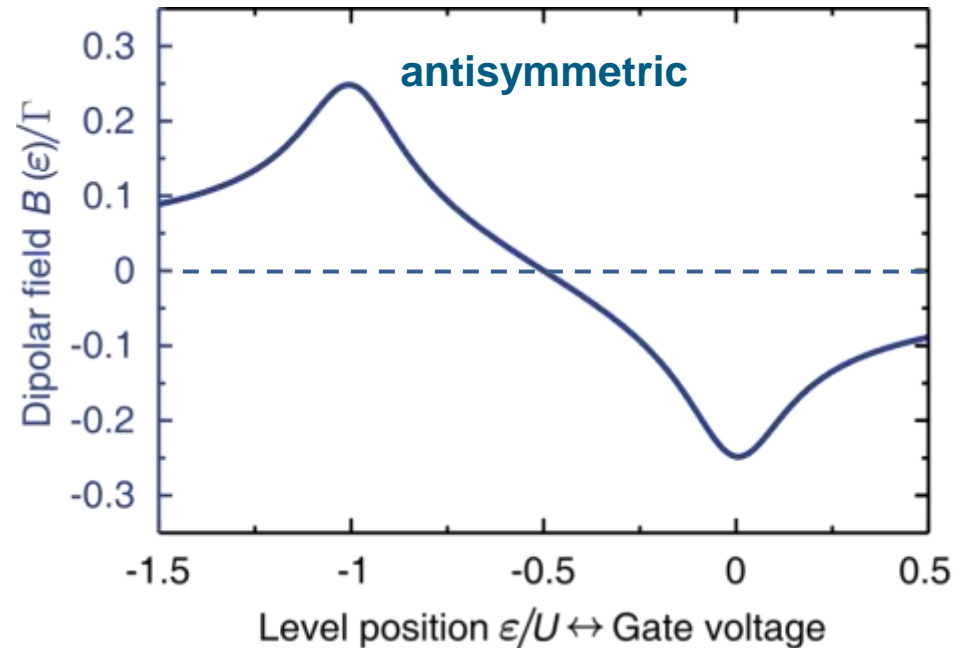
Dipolar vs. quadrupolar exchange field

$$\mathcal{H}_{\text{eff}} = BS_z + DQ_{zz}$$

Perturbation theory $\Gamma \ll T$

$$B = B_0 - B_2 \rightarrow B \propto p\Gamma$$

$$B_n = \sum_{q=L,R} \mathcal{P} \int \frac{d\omega}{2\pi} \frac{p_q \Gamma_q f(\omega)}{\omega - \epsilon - nU/2}$$



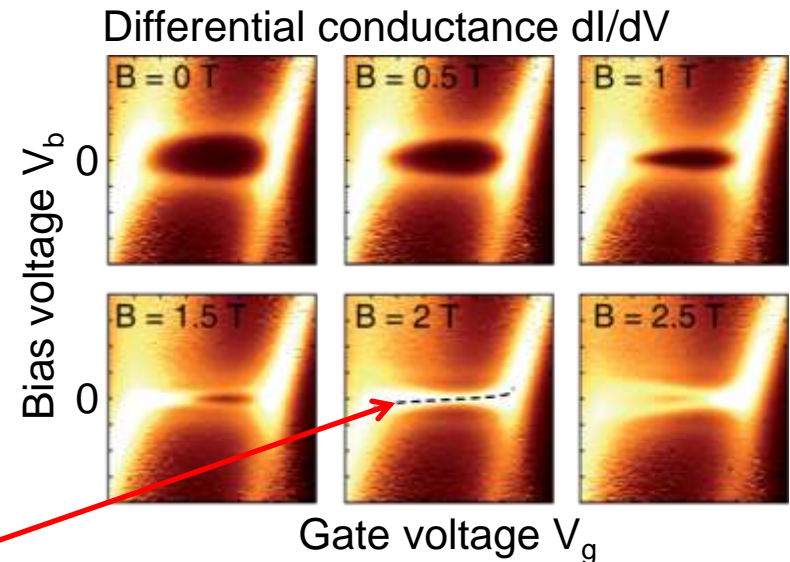
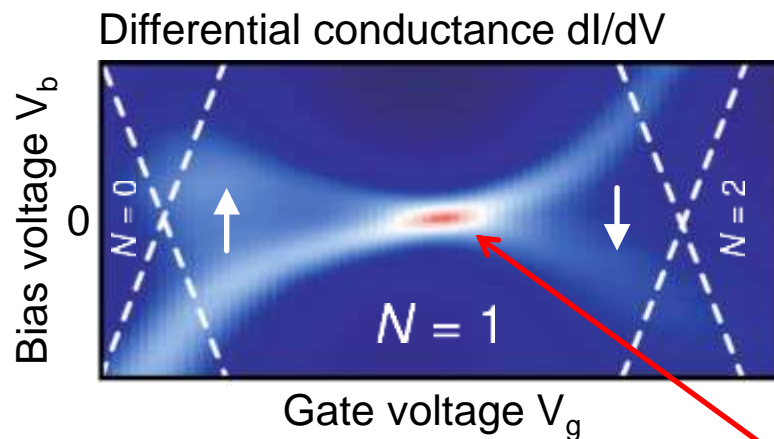
Quadrupolar field DQ_{zz}/Γ

Dipolar vs. quadrupolar exchange field

Experimental evidences of dipolar field in CNT QDs

Gate-tunable

Magnetic field-tunable $B_{\text{ext}} \neq 0$



restored Kondo effect

Hauptman *et al.*, Nature Phys. **4**, 373 (08)

Gaass *et al.*, PRL **107**, 176808 (11)

Dipolar vs. quadrupolar exchange field

$$\mathcal{H}_{\text{eff}} = BS_z + DQ_{zz}$$

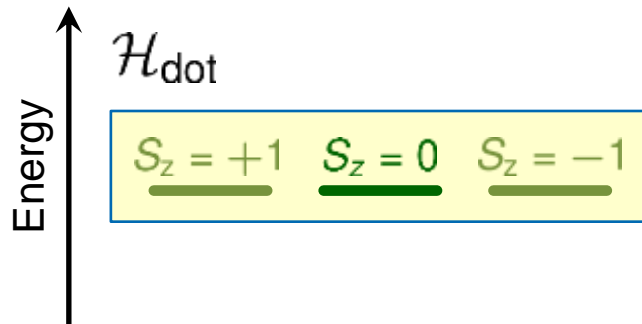
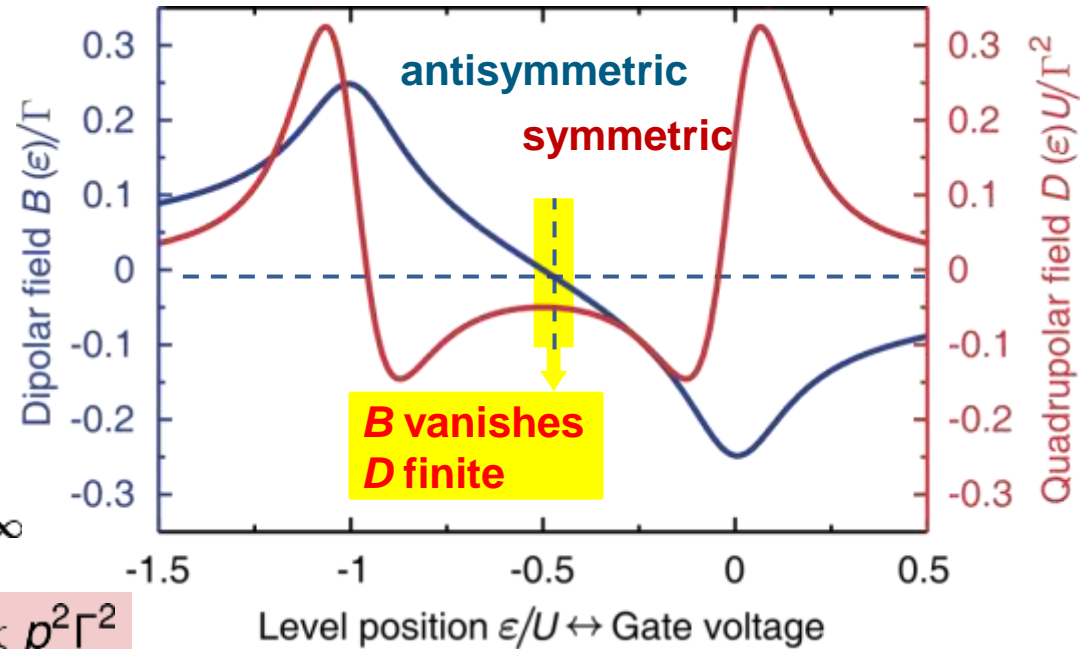
Perturbation theory $\Gamma \ll T$

$$B = B_0 - B_2 \rightarrow B \propto p\Gamma$$

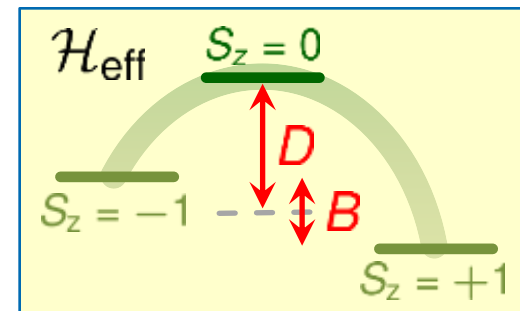
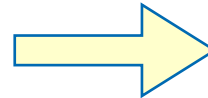
$$B_n = \sum_{q=L,R} \mathcal{P} \int \frac{d\omega}{2\pi} \frac{p_q \Gamma_q f(\omega)}{\omega - \epsilon - nU/2}$$

deep in Coulomb blockade regime & $K \rightarrow \infty$

$$D \approx -B_0 \frac{dB_0}{d\epsilon} - B_2 \frac{dB_2}{d(-\epsilon)} \rightarrow D \propto p^2 \Gamma^2$$



attach
ferromagnets



Quadrupolar exchange field

Strong coupling regime $\Gamma \gg T$

➔ all-electric superparamagnet has the characteristic properties of a **spintronic exchange field**: **electric tunability** and **scaling with tunnel-coupling (Γ) and spin-polarization (p)**

Dipolar exchange field

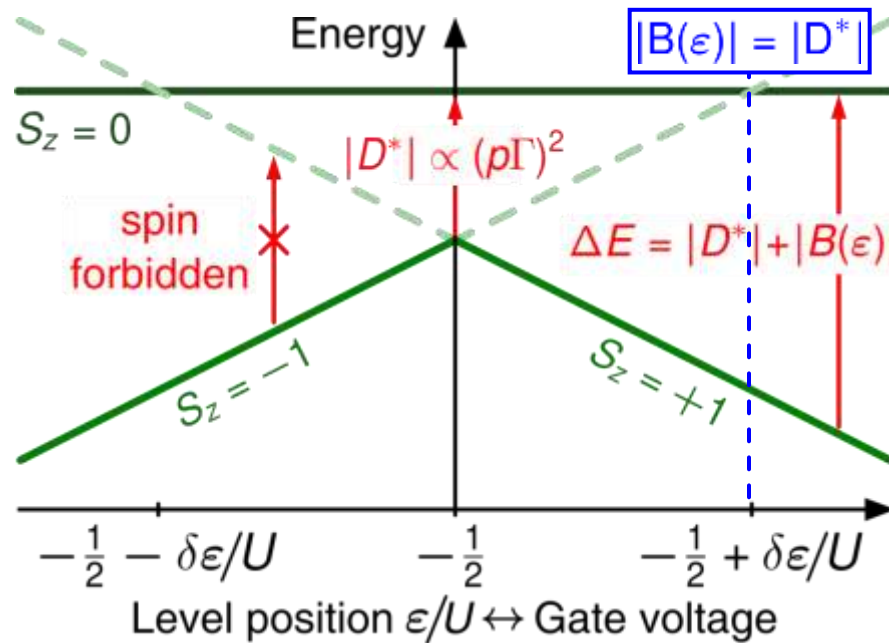
Quadrupolar exchange field

$$B \propto p\Gamma$$

vs.

$$D \propto p^2\Gamma^2$$

➔ **IDEA**: tune gate voltage to eliminate dipolar exchange field



$$T \ll U \ll W$$

$$D^* \equiv -\frac{1}{\pi^2} \frac{(p\Gamma)^2}{U} \ln \frac{2W}{U}$$

$$B(\epsilon) \approx -\frac{2}{\pi} p\Gamma \left(\frac{\epsilon}{U} + \frac{1}{2} \right)$$

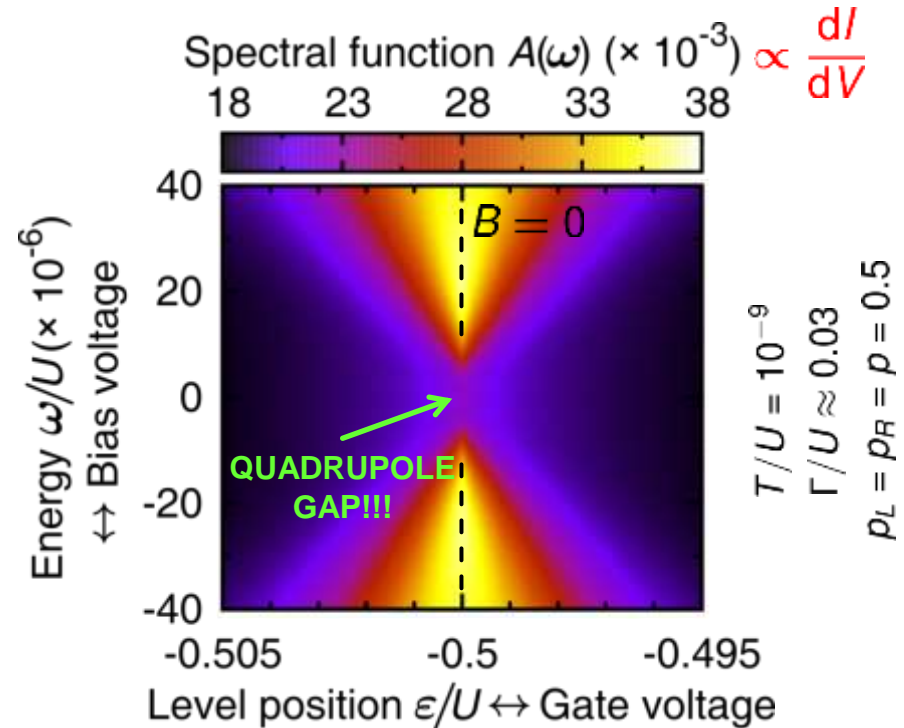
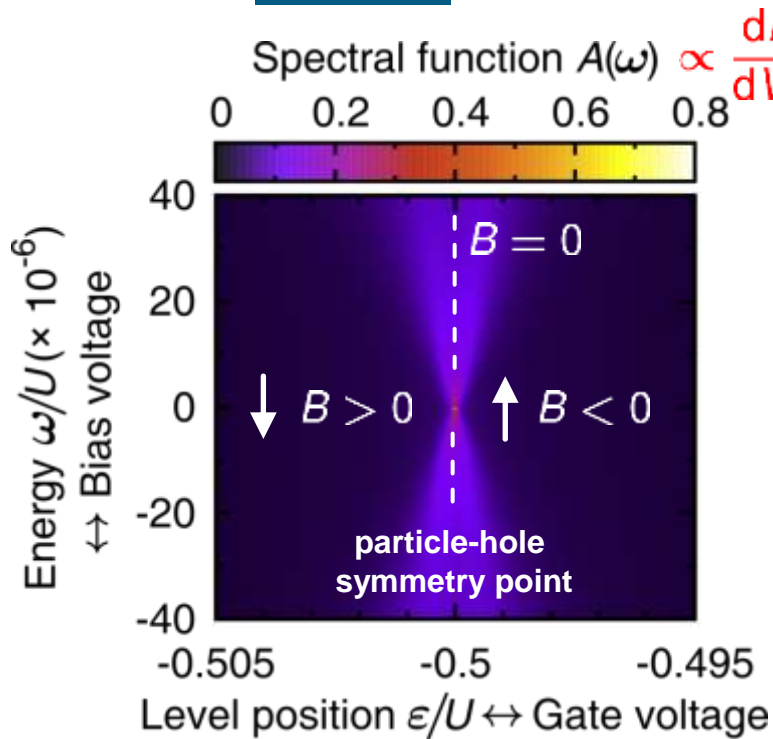
$$\delta\epsilon = \frac{\pi}{2} \frac{|D^*|U}{p\Gamma}$$

Low- vs. high-spin quantum dots

$$A(\omega) = 2\pi \sum_{\sigma} \Gamma_{\sigma} \frac{a_{\sigma}(-\omega) + a_{\sigma}(\omega)}{2}$$

$S = \frac{1}{2} \rightarrow K = 0$

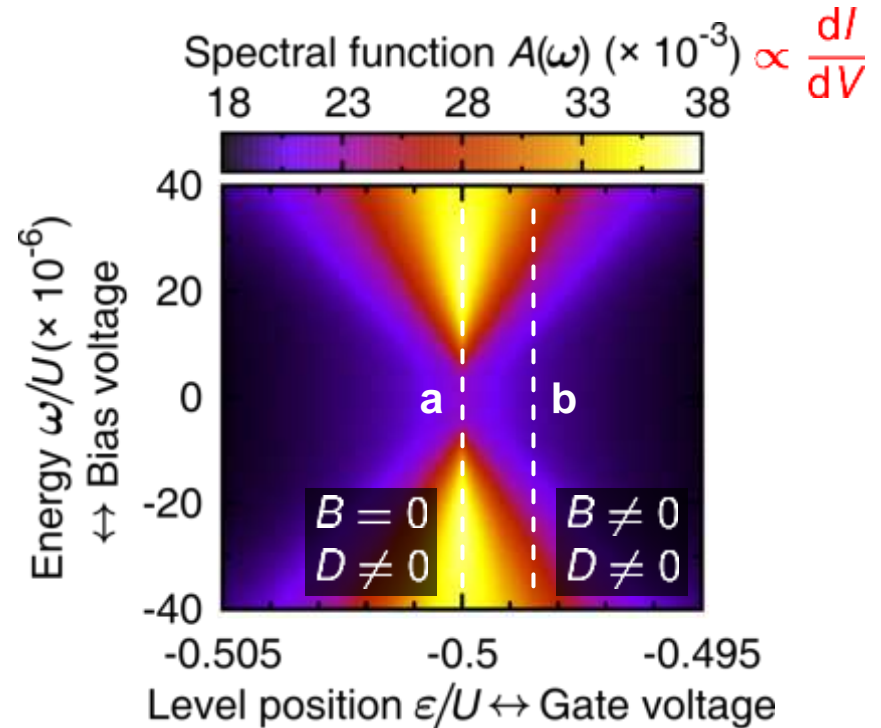
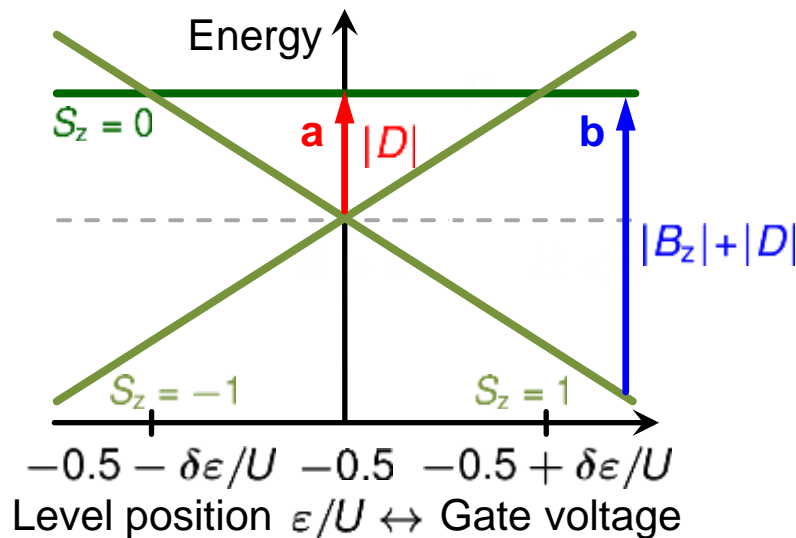
$S = 1 \rightarrow$ finite exchange K



Numerical renormalization group (NRG):

K. Wilson, RMP **47**, 773 (75); R. Bulla et al., RMP **80**, 395 (08); Weichselbaum & von Delft, PRL **99**, 076402 (07); Toth et al., PRB **78**, 245109 (08); Budapest fDM-NRG code – O. Legeza et al., arXiv:0809.3143 (08)

Spectroscopic signatures of quadrupolar field

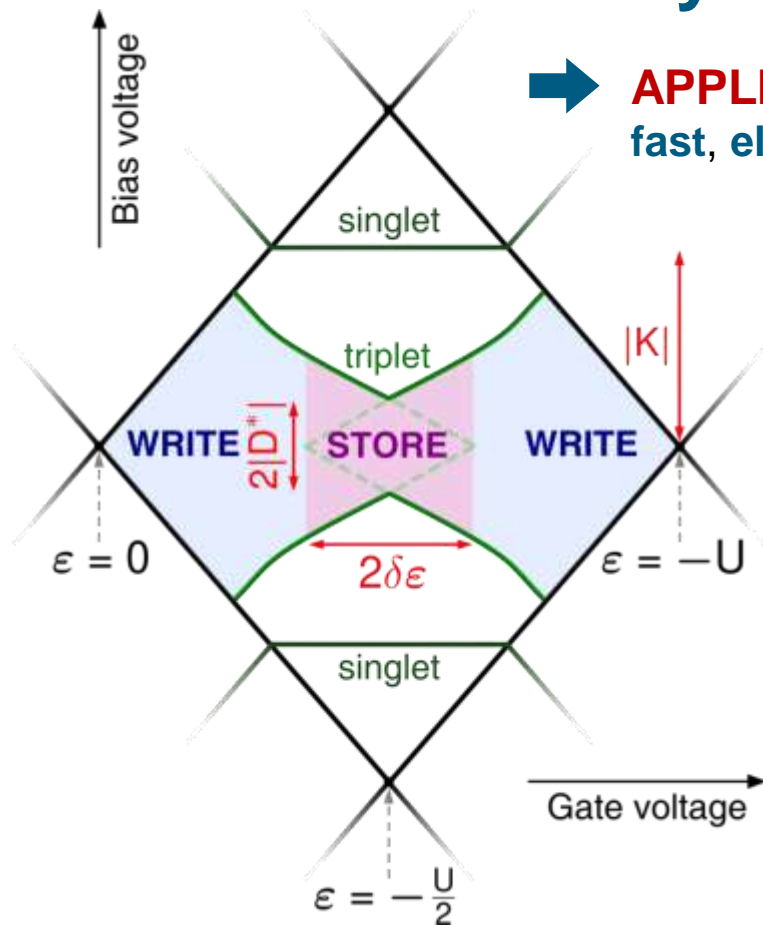


➔ inelastic cotunneling signatures as for **SMM** or **magnetic adatom**, but **NO intrinsic anisotropy**

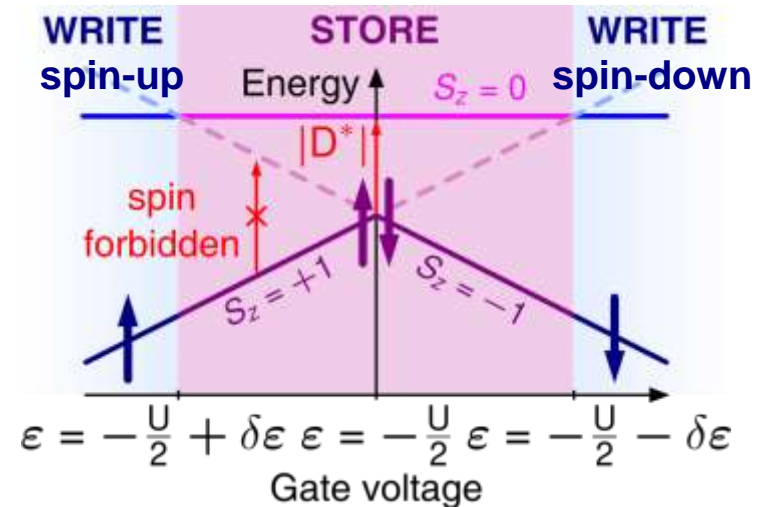
Nature Phys. **9**, 801 (13);

Experiments with intrinsic anisotropy signatures: Hirjibehedin *et al.*, Science **312**, 1021 (06); Jo *et al.*, Nano Lett. **6**, 2014 (06); Zyazin *et al.*, Nano Lett. **10**, 3307 (10); Kahle *et al.*, Nano Lett. **12**, 518 (12)

On-demand bistability: writing and storing spin



➔ **APPLICATION:** quadrupolar field as a new means for fast, electrical control of nanomagnetic memory cells



$$D^* \approx -\frac{1}{\pi^2} \frac{(p\Gamma)^2}{U} \ln \frac{2W}{U} \quad \delta\epsilon = \frac{\pi}{2} \frac{|D^*|U}{p\Gamma}$$

➔ the spin can be switched by **electrically tuning** from the neutral 'STORE' regime to 'WRITE spin-up' or 'WRITE spin-down' regime, returning then again to the 'STORE' regime where $|B| \ll |D^*|$

➔ robust against perturbations on energy scales $< |D^*|$

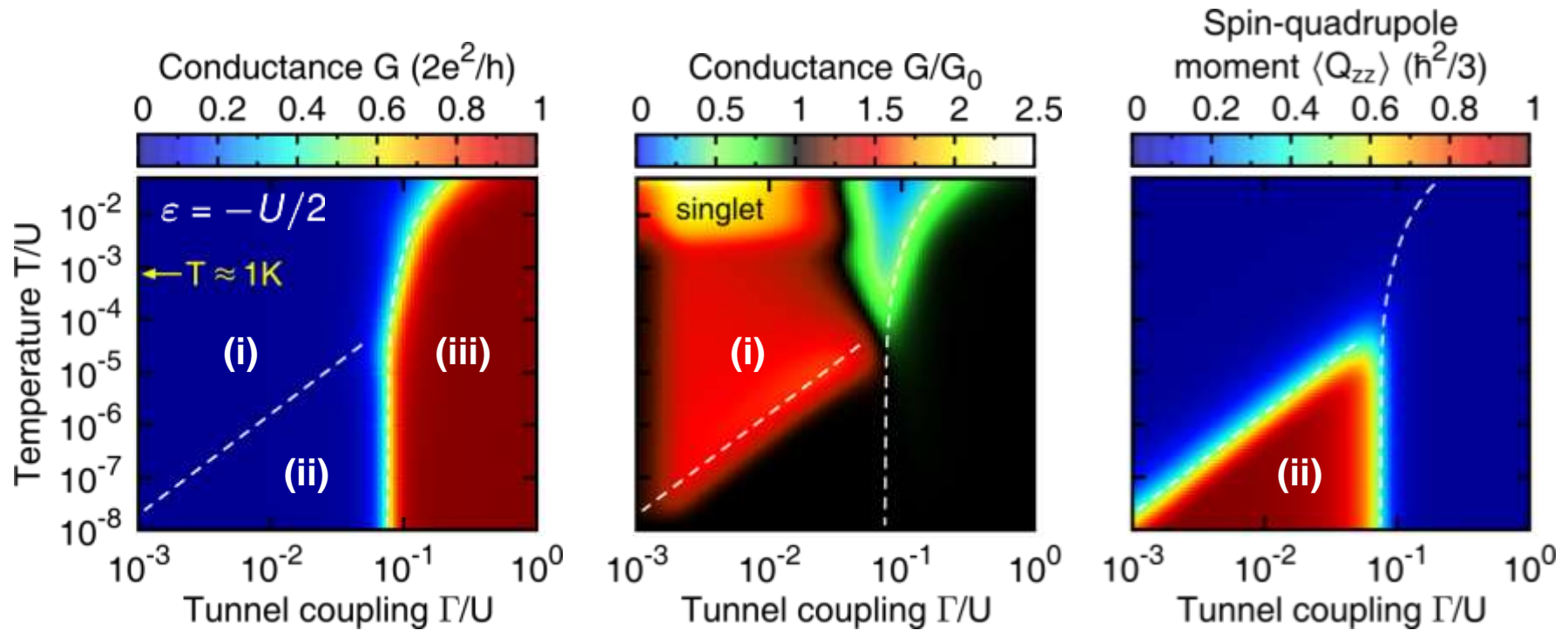
Conclusions and outlook

- ➔ nanoscopic systems with uniaxial magnetic anisotropy = **magnetic bistability**
 - building blocks for a memory cell
 - spin-polarized currents for manipulation of the magnetic state of the system
- ➔ proximity-induced **spin-anisotropy** in high-spin **spin-isotropic system**
KEY IDEA: spin-anisotropy = spintronic quantity
- ➔ tunnel-induced exchange fields:
 - **DIPOLAR** ~ *pseudo* magnetic field ~ spin torque
 - **QUADRUPOLAR** ~ spin-anisotropy tensor *a la* molecular magnetism
- ➔ scaling of cotunneling gap with **tunnel coupling Γ** and **spin polarization p**
- ➔ full **electric tunability** of all terms in magnetic Hamiltonian

For details see: Misiorny, Hell & Wegewijs, Nature Phys. **9**, 801 (13)
 Misiorny & Barnaś, PRL **111**, 046603 (13)
 Misiorny, Weymann & Barnaś, PRB **86**, 245415 (12)
 Hell, Das & Wegewijs, PRB **88**, 115435 (13)

Thank you for your attention

Competition between spintronic anisotropy and Kondo effect



- (i) **paramagnetic regime** $T \gtrsim |D^*(\Gamma)|$ and $T_K(\Gamma, D^*(\Gamma))$
- (ii) **superparamagnetic regime** $|D^*(\Gamma)| \gtrsim T$ and $T_K(\Gamma, D^*(\Gamma))$
- (iii) **Kondo screened regime** $T_K(\Gamma, D^*(\Gamma)) \gtrsim |D^*(\Gamma)|$